

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

**TC74VHCT125AF, TC74VHCT125AFN, TC74VHCT125AFT**  
**TC74VHCT126AF, TC74VHCT126AFN, TC74VHCT126AFT**

**TC74VHCT125AF / AFN / AFT QUAD BUS BUFFER**  
**TC74VHCT126AF / AFN / AFT QUAD BUS BUFFER**

(Note) : The JEDEC SOP (FN) is not available in Japan.

The TC74VHCT125A / 126A are high speed CMOS QUAD BUS BUFFERS fabricated with silicon gate C<sup>2</sup>MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Shottky TTL while maintaining the CMOS low power dissipation.

The TC74VHCT125A requires the 3-state control input  $\bar{G}$  to be set high to place the output into the high impedance state, whereas the TC74VHCT126A requires the control input G to be set low to place the output into high impedance.

The input voltage are compatible with TTL output voltage. This device may be used as a level converter for interfacing 3.3 V to 5 V system.

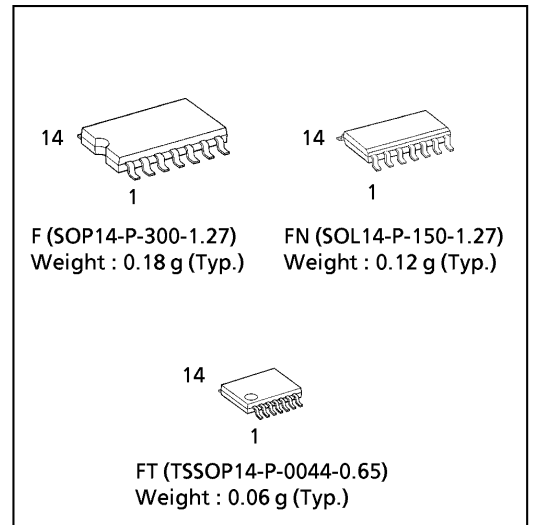
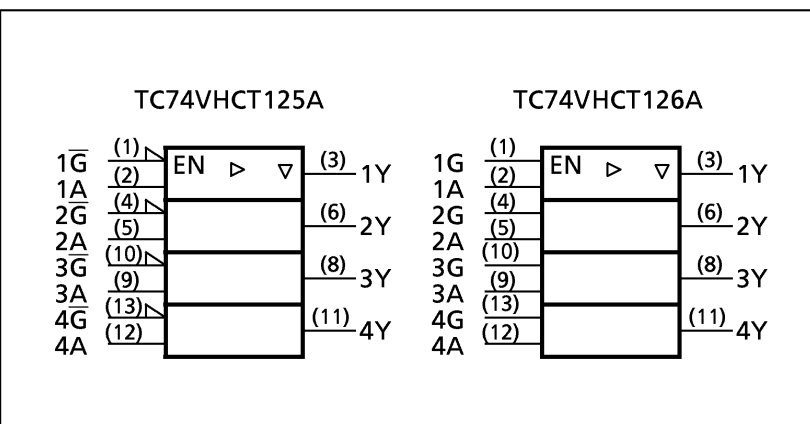
Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output\*1 pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

\*1:  $V_{cc} = 0 V$

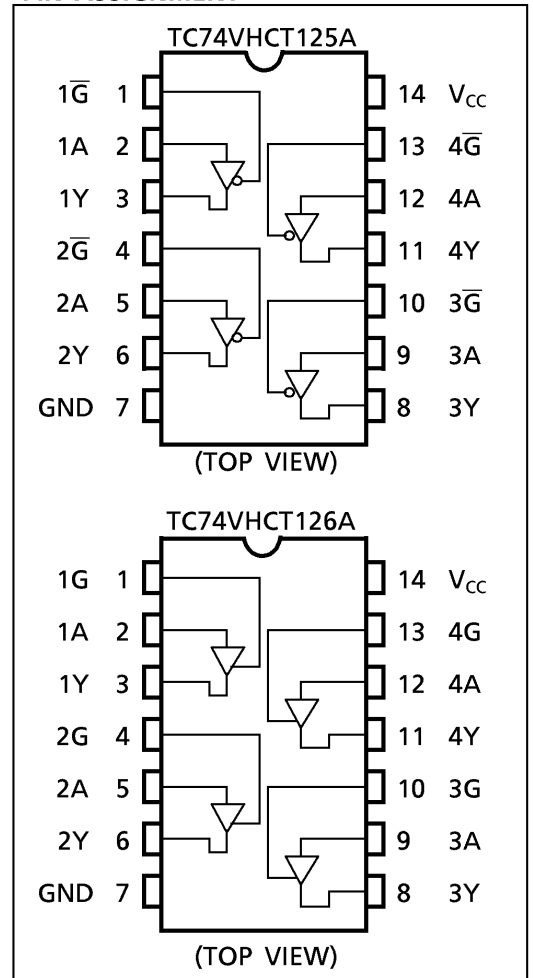
**FEATURES:**

- High Speed.....  $t_{pd} = 3.8 \text{ ns (typ.) at } V_{CC} = 5 V$
- Low Power Dissipation.....  $I_{CC} = 4 \mu A \text{ (Max.) at } T_a = 25^\circ C$
- Compatible with TTL outputs.....  $V_{IL} = 0.8 V \text{ (Max.)}$   
 $V_{IH} = 2.0 V \text{ (Min.)}$
- Power Down Protection is provided on all inputs and outputs.
- Balanced Propagation Delays.....  $t_{pLH} \approx t_{pHL}$
- Low Noise.....  $V_{OLP} = 0.8 V \text{ (Max.)}$
- Pin and Function Compatible with the 74 series (74AC / HC / F / ALS / LS etc.) 125 / 126 type.

**IEC LOGIC SYMBOL**



**PIN ASSIGNMENT**



**TRUTH TABLE**

TC74VHCT125A			TC74VHCT126A		
INPUTS		OUTPUTS	INPUTS		OUTPUTS
$\bar{G}$	A	Y	G	A	Y
H	X	Z	L	X	Z
L	L	L	H	L	L
L	H	H	H	H	H

X: Don't Care  
Z: High Impedance

X: Don't Care  
Z: High Impedance

**ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	$V_{CC}$	-0.5~7.0	V
DC Input Voltage	$V_{IN}$	-0.5~7.0	V
DC Output Voltage	$V_{OUT}$	-0.5~7.0 (Note 1)	V
		-0.5 ~ $V_{CC}$ + 0.5 (Note 2)	
Input Diode Current	$I_{IK}$	-20	mA
Output Diode Current	$I_{OK}$	±20 (Note 3)	mA
DC Output Current	$I_{OUT}$	±25	mA
DC Vcc/Ground Current	$I_{CC}$	±50	mA
Power Dissipation	$P_D$	180	mW
Storage Temperature	$T_{stg}$	-65~150	°C

(Note 1) : Output in Off-State

(Note 2) : High or Low State.  $I_{OUT}$  absolute maximum rating must be observed.

(Note 3) :  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$

**RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	$V_{CC}$	4.5~5.5	V
Input Voltage	$V_{IN}$	0~5.5	V
Output Voltage	$V_{OUT}$	0~5.5 (Note 4)	V
		0~ $V_{CC}$ (Note 5)	
Operating Temperature	$T_{opr}$	-40~85	°C
Input Rise and Fall Time	dt / dV	0~20	ns / V

(Note 4) : Output in Off-State

(Note 5) : High or Low State

## DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	CONDITON	$V_{CC}$ (V)	Ta = 25°C			Ta = -40~85°C		UNIT	
				MIN.	TYP.	MAX.	MIN.	MAX.		
High - Level Input Voltage	$V_{IH}$		4.5~5.5	2.0	—	—	2.0	—	V	
Low - Level Input Voltage	$V_{IL}$		4.5~5.5	—	—	0.8	—	0.8	V	
High - Level Output Voltage	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -50 \mu A$	4.5	4.40	4.50	—	4.40	—	V
			$I_{OH} = -8 \text{ mA}$	4.5	3.94	—	—	3.80	—	
Low - Level Output Voltage	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 50 \mu A$	4.5	—	0.0	0.1	—	0.1	V
			$I_{OL} = 8 \text{ mA}$	4.5	—	—	0.36	—	0.44	
Input Leakage Current	$I_{IN}$	$V_{IN} = 5.5 \text{ V}$ or GND	0~5.5	—	—	$\pm 0.1$	—	$\pm 1.0$	$\mu A$	
3-State Output Off-state Current	$I_{OZ}$	$V_{IN} = V_{IH}$ or $V_{IL}$ $V_{OUT} = V_{CC}$ or GND	5.5	—	—	$\pm 0.25$	—	$\pm 2.50$		
Quiescent Supply Current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND	5.5	—	—	4.0	—	40.0		
	$I_{CCT}$	PER INPUT : $V_{IN} = 3.4 \text{ V}$ OTHER INPUT : $V_{CC}$ or GND	5.5	—	—	1.35	—	1.50	mA	
Output Leakage Current	$I_{OPD}$	$V_{OUT} = 5.5 \text{ V}$	0	—	—	0.5	—	5.0	$\mu A$	

AC ELECTRICAL CHARACTERISTICS (Input  $t_r = t_f = 3$  ns)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = -40~85°C		UNIT	
		$V_{CC}$ (V)	CL (pF)	MIN.	TYP.	MAX.	MIN.	MAX.		
Propagation Delay Time	$t_{pLH}$	5.0 ± 0.5	15	—	3.8	5.5	1.0	6.5	ns	
	$t_{pHL}$		50	—	5.3	7.5	1.0	8.5		
Output Enable Time	$t_{pZL}$	RL = 1 kΩ	15	—	3.6	5.1	1.0	6.0		
	$t_{pZH}$		50	—	5.1	7.1	1.0	8.0		
Output Disable Time	$t_{pLZ}$	RL = 1 kΩ	5.0 ± 0.5	50	—	6.1	8.8	1.0		10.0
	$t_{pHZ}$									
Output to Output Skew	$t_{oS LH}$ $t_{oS HL}$	(Note 6)	5.0 ± 0.5	50	—	—	1.0	—	1.0	
Input Capacitance	$C_{IN}$				—	4	10	—	10	pF
Output Capacitance	$C_{OUT}$				—	6	—	—	—	
Power Dissipation Capacitance (Note 7)	$C_{PD}$	TC74VHCT125A			—	14	—	—	—	
		TC74VHCT126A			—	15	—	—	—	

(Note 6) : Parameter guaranteed by design.  $t_{oS LH} = |t_{pLH m} - t_{pLH n}|$ ,  $t_{oS HL} = |t_{pHL m} - t_{pHL n}|$

(Note 7) :  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

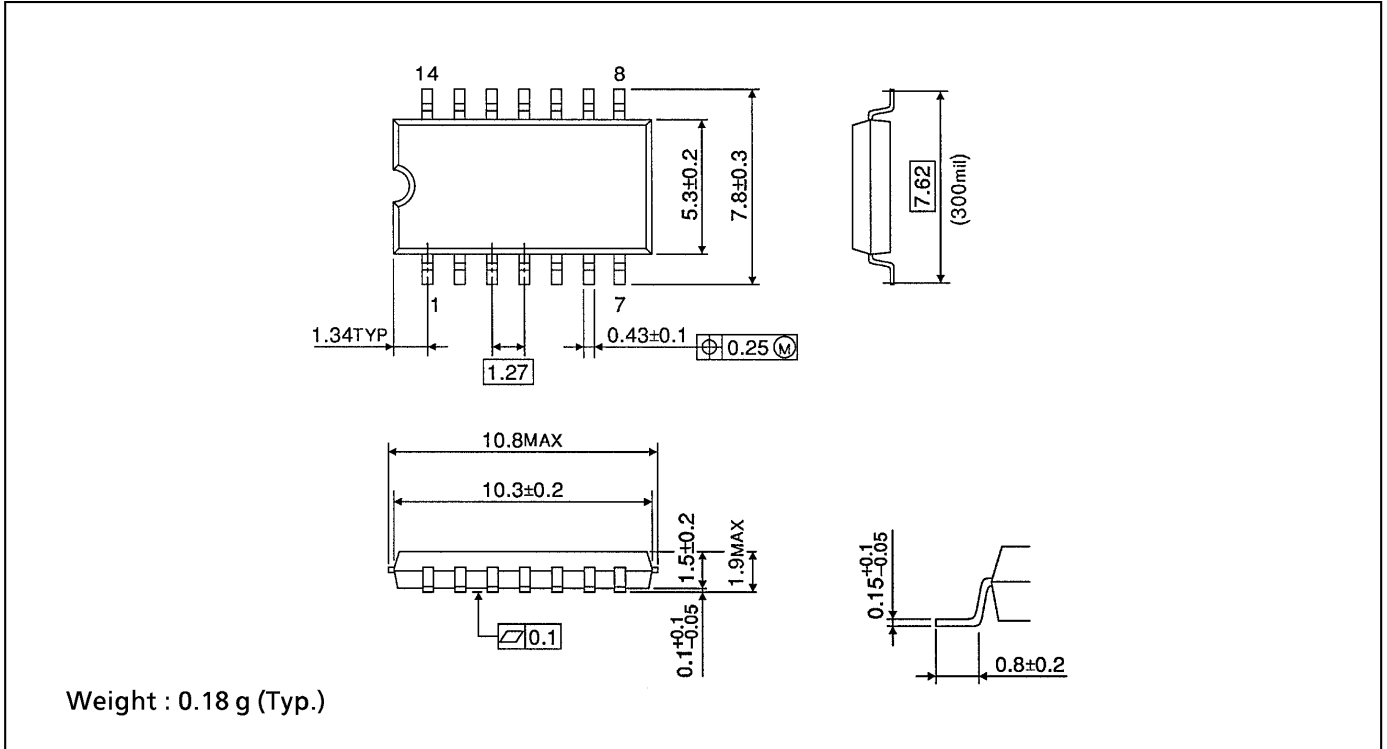
$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per Gate)}$$

NOISE CHARACTERISTICS (Input  $t_r = t_f = 3$  ns)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C		UNIT
		$V_{CC}$ (V)		TYP.	LIMIT	
Quiet Output Maximum Dynamic $V_{OL}$	$V_{OLP}$	$C_L = 50$ pF	5.0	0.5	0.8	V
Quiet Output Minimum Dynamic $V_{OL}$	$V_{OLV}$	$C_L = 50$ pF	5.0	-0.5	-0.8	V
Minimum High Level Dynamic Input Voltage	$V_{IHD}$	$C_L = 50$ pF	5.0	—	2.0	V
Maximum Low Level Dynamic Input Voltage	$V_{ILD}$	$C_L = 50$ pF	5.0	—	0.8	V

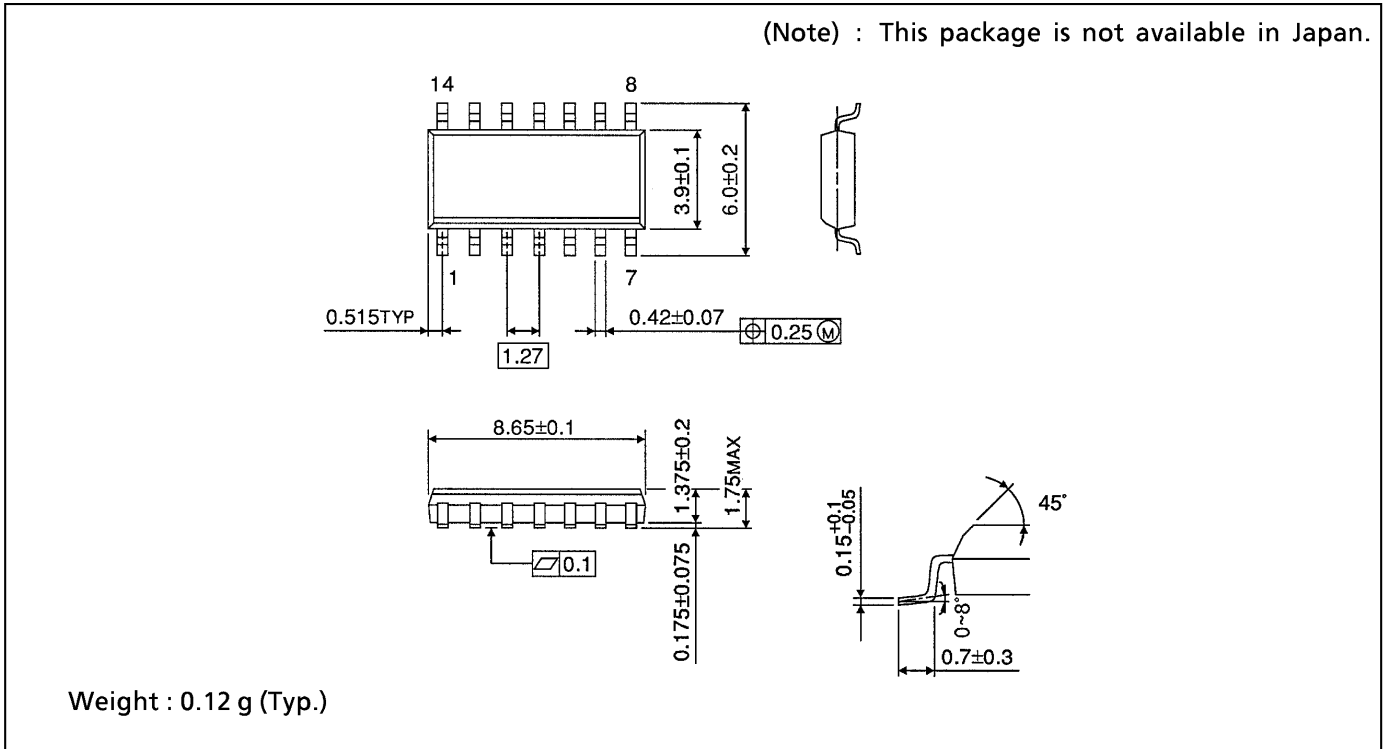
**SOP 14 PIN (200 mil BODY) PACKAGE DIMENSIONS (SOP14-P-300-1.27)**

Unit in mm



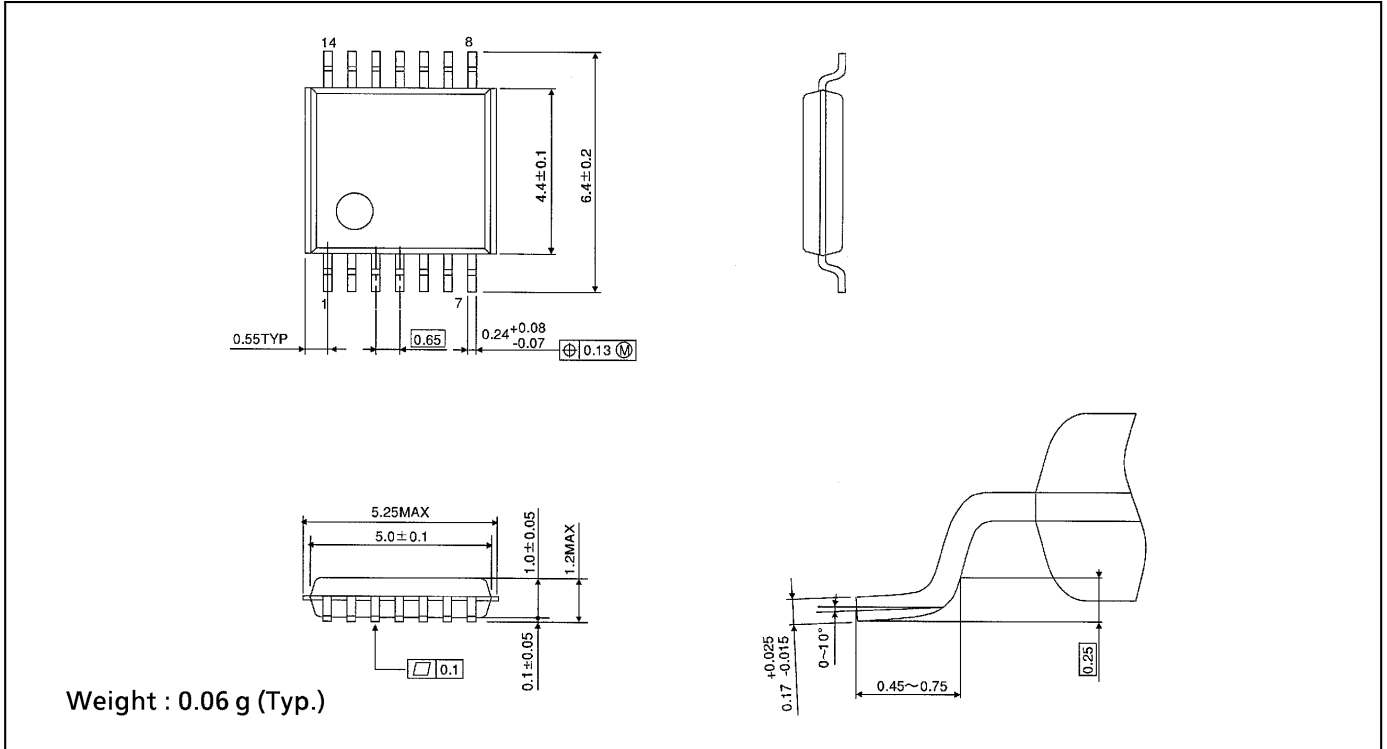
**SOP 14 PIN (150 mil BODY) PACKAGE DIMENSIONS (SOP14-P-150-1.27)**

Unit in mm



**TSSOP 14 PIN PACKAGE DIMENSIONS (TSSOP14-P-0044-0.65)**

Unit in mm



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